NSN 5961-01-375-0810

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-375-0810 **Inclosure Material:** Plastic **Overall Length:** Between 2.8 millimeters and 3.0 millimeters **Overall Height:** 1.1 millimeters **Overall Width:** Between 1.2 millimeters and 1.4 millimeters **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 4.4 regulator voltage, dc and 5.0 regulator voltage, dc **Current Rating Per Characteristic:** 5.00 milliamperes all primaries horsepower metric **Power Rating Per Characteristic:** 300.0 milliwatts any acceptable preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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